## NSN 5962-01-492-5823

Memory Microcircuit - Page 1 of 1



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| Maximum Power Dissipation Rating:  |
|--|
| 1.2 watts  |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| End Application:   |
| Aircraft, starlifter c-141   |
| Features Provided:   |
| Ultraviolet erasable   |
| Inclosure Configuration:   |
| Dual-in-line   |
| Output Logic Form:   |
| Complementary-metal oxide-semiconductor logic  |
| Input Circuit Pattern:   |
| 22 input   |
| Product Name:  |
| Microcircuit, digital memory cmos, uv erasable programming logic array   |
| Voltage Rating And Type Per Characteristic:  |
| -0.5 volts power source and 7.0 volts power source   |
| Time Rating Per Chacteristic:  |
| 10.00 nanoseconds af output megawatts  |
| Memory Device Type:  |
| Pal  |
| Special Features:  |
| This is an altered item. Altered item shall be made from unprogrammed device p/n 5962-8753906lx following programming procedures |
| 5137911-ei   |
| Test Data Document:  |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).               |
| Terminal Type And Quantity:  |
| 24 printed circuit   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
| <del>-</del>   |
| Demilitarization:  |
| Yes - demil/mli  |
| Fiig:  |
| A458a0   |
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